

SANYO Semiconductors DATA SHEET

SCH1301—General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-12	V
Gate-to-Source Voltage	VGSS		±8	V
Drain Current (DC)	ID		-2.4	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-9.6	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linis
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0	-12			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-4V, V _{GS} =0			-1	μΑ
		V _{DS} =-12V, V _{GS} =0			-10	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±6.4V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=-6V, ID=-1mA	-0.3		-1.0	V
Forward Transfer Admittance	yfs	V _{DS} =-6V, I _D =-1.3A	2.52	4.2		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-1.3A, V _G S=-4.5V		90	120	mΩ
	RDS(on)2	ID=-0.7A, VGS=-2.5V		125	175	mΩ
	R _{DS} (on)3	I _D =-0.3A, V _G S=-1.8V		165	280	mΩ
	R _{DS} (on)4	I _D =-0.1A, V _G S=-1.5V		330	580	mΩ
Input Capacitance	Ciss	VDS=-6V, f=1MHz		450		pF
Output Capacitance	Coss	V _{DS} =-6V, f=1MHz		100		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-6V, f=1MHz		85		pF

Marking: JA Continued on next page.

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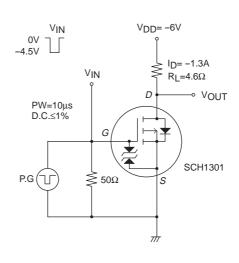
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onne
Turn-ON Delay Time	td(on)	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		70		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		65		ns
Fall Time	tf	See specified Test Circuit.		50		ns
Total Gate Charge	Qg	V _{DS} =-6V, V _{GS} =-4.5V, I _D =-2.6A		6.5		nC
Gate-to-Source Charge	Qgs	V _{DS} =-6V, V _{GS} =-4.5V, I _D =-2.6A		0.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-6V, V _{GS} =-4.5V, I _D =-2.6A		2.0		nC
Diode Forward Voltage	V _{SD}	I _S =-2.6A, V _{GS} =0		-0.87	-1.5	V

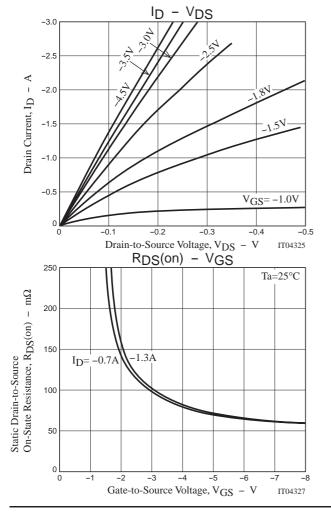
Package Dimensions

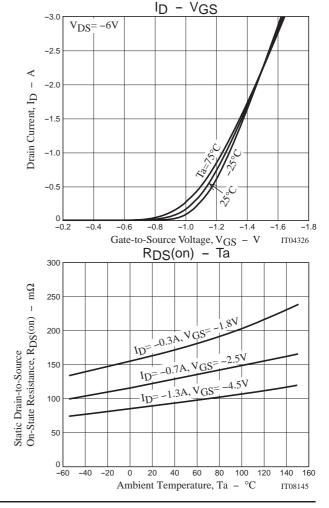
unit: mm 2221A

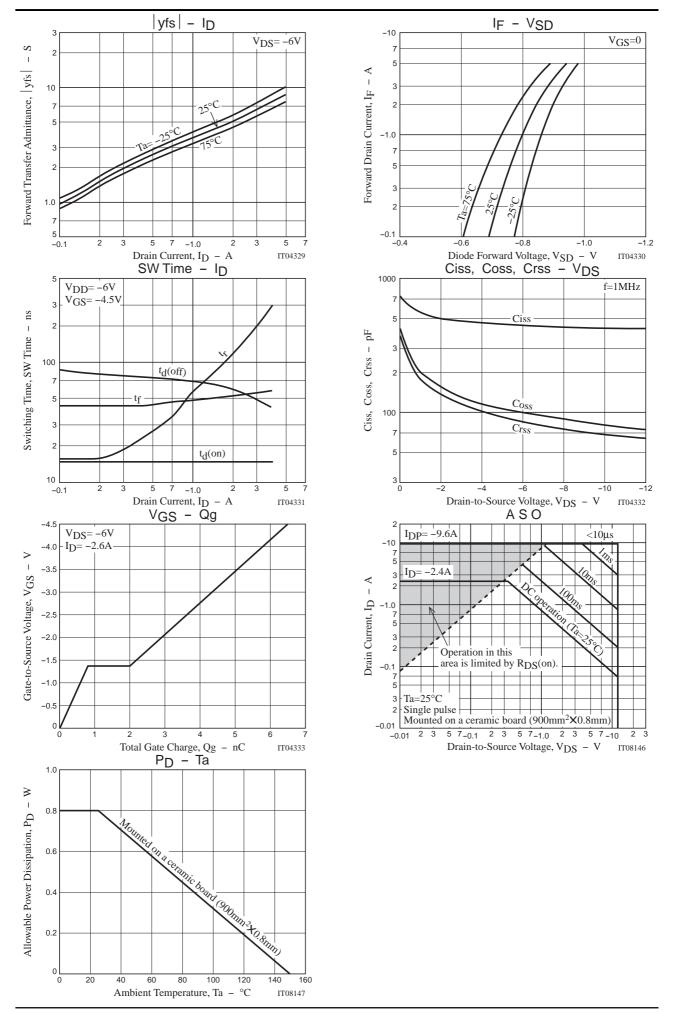
1.6 0.2 0.2 0.2 1 : Drain 2 : Drain 3 : Gate 4 : Source 5 : Drain 6 : Drain SANYO : SCH6

Switching Time Test Circuit









Note on usage : Since the SCH1301 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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